# **Supporting Information**

# **Promoted thermoelectric performance in cubic-phase GeTe** *via* **grain-boundary phase elimination under phase diagram guidance**

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#### **Experimental details**

#### **Materials fabrication:**

Ge (pieces, 99.99 %), Te (particle, 99.99 %), Ag (chunks, 99.99 %) and Sb (granules, 99.99 %) were used as raw materials to synthesize  $(GeTe)<sub>x</sub>(Ag<sub>0.8</sub>Sb<sub>1.2</sub>Te<sub>2.2</sub>)<sub>100-x</sub> (x = 75, 76, 77, 78, 79)$ and (GeTe)<sub>78</sub>(Ag<sub>1- $\delta$ </sub>Sb<sub>1+ $\delta$ </sub>Te<sub>2+ $\delta$ </sub>)<sub>22</sub> ( $\delta$  = 0.2, 0.21, 0.22, 0.23, 0.24) (written as:  $\delta$ -TAGS-78) utilizing melting and quenching method. These mixtures were load into evacuated quartz tubes and encapsulated with  $10^{-4}$  Pa, following put into the furnace and heated up to  $1173K$  in 12 h and kept there for 12 hours before being quenched in water. Then, the as-obtained ingots were annealed at 773 K for 24 h. After that, the obtained ingots were hand-ground into powders in agate mortar, then poured into a  $\phi$ 15 mm graphite die and sintered using spark plasma sintering (SPS) method (Sinter Land INC, Japan) under 50 MPa and 723K in vacuum (< 6 Pa) for 5min.

The obtained bulk samples were cut into a block with cross section of  $3\times3\times12$  mm<sup>3</sup> for electrical transport measurements and  $6 \times 6 \times 2$  mm<sup>3</sup> for thermal diffusion coefficient (*D*) measurements.

#### **Thermoelectric properties measurements:**

The commercial ZEM-3 apparatus (Ulvac-Riko, Japan) was performed to measure the Seebeck coefficient and electrical conductivity under dilute helium atmosphere. The uncertainties of measurements were estimated to be about 5%. The thermal conductivity *κ* was calculated *via*  $\kappa = D C_p \rho$ , where *D* is thermal diffusivity coefficient can be obtained using the LFA-467 (Netzsch, Germany) laser flash under nitrogen atmosphere, *ρ* is the mass density measured using the Archimedes method (Mettler Toledo, Model XSE105DU), and *C*<sup>p</sup> is the heat capacity which was estimated by the Dulong-Petit limit. The uncertainty of thermal conductivity was estimated to be about 7%. The electronic thermal conductivity  $(\kappa_{ele})$  was calculated according to Wiedemann-Franz law:  $\kappa_{ele} = \sigma LT$ , where the Lorenz factor (*L*) was roughly calculated by the equation:  $L = 1.5 + \exp(-|S|/116)$ .<sup>[1]</sup> Considering the uncertainties of all the parameters, the uncertainty of the calculated *ZT* was about 13%. Room temperature carrier concentration and carrier mobility were measured with Van der Pauw method (Lake Shore 8400 Series, Model 8404, USA), with an uncertainty of about 10%.

#### **Structural characterization**

Powder X-ray diffraction using a diffractometer (MiniFlex600, Rigaku, Tokyo, Japan) was

conducted to analyze the crystal structures. With Cu Kα radiation ( $\lambda = 1.5418 \text{ Å}$ , 40 kV, 40 mA), while the scanning rate of 10° min<sup>-1</sup> from  $2\theta = 20$ ° to 80°.

Transmission electron microscopy (TEM), Cs-corrected high-angle angular dark fieldscanning transmission electron microscopy (HAADF-STEM) and energy dispersive X-ray mapping (EDX) experiments were performed using a FEI Titan Themis 60-300 kV microscope equipped with a Super-X detector and operating at 300 kV.

#### **Mechanical properties**

The Vickers hardness and Young's modulus were measured through a nano-indentation technique (iMicro KLA, USA).

The temperature-dependent relative length variation was measured on a thermal dilatometer (DIL 402 Expedis Supreme, Netzsch), where the slope of corresponding curves indicates the coefficient of thermal expansion.

#### **Weighted mobility**

The temperature-dependent weighted mobility  $(\mu_w)$  was derived from the experimental electrical conductivity  $\sigma$  and Seebeck coefficient *S* proposed by G. J. Snyder et al:<sup>[2]</sup>

$$
\mu_{\rm w} = 331 \left( \frac{1}{\rho} \right) \left( \frac{1}{300} \right)^{-\frac{3}{2}} \left[ \frac{\exp[\frac{|S|}{k_{\rm B}/\mathrm{e}} - 2]}{1 + \exp[-5(\frac{|S|}{k_{\rm B}/\mathrm{e}} - 1)]} + \frac{\frac{3}{\pi^2} \frac{|S|}{k_{\rm B}/\mathrm{e}}}{1 + \exp[5(\frac{|S|}{k_{\rm B}/\mathrm{e}} - 1)]} \right]
$$

where  $\mu_w$  is the weighted mobility,  $\rho$  is the electrical resistivity measured in m $\Omega$  cm, *T* is the absolute temperature in K, S is the Seebeck coefficient, and  $k_B/e = 86.3 \mu V K^{-1}$ .

#### **Thermoelectric generator fabrication**

The thermoelectric power generator (TEG) with an overall size of  $20\times20$  mm<sup>2</sup>, in which composed of eight-pair of *p*-type legs  $(GeTe)_{78}(Ag_{0.77}Sb_{1.23}Te_{2.23})_{22}$  and *n*-types leg  $Pb_{0.985}Sb_{0.015}Te$ . The SPS-sintered *p*- and *n*-type bulk was cut into thermoelectric legs with geometric dimensions sizes of  $\sim$ 3.5 $\times$ 3.5mm<sup>2</sup>, and Ni as a diffusion barrier material was electroplated to the as-obtained legs. The TEG was assembled with soldering the thermoelectric pairs onto a copper-clad plate at the hot side using tin-based high-temperature solder, whereas directly bonding a copper substrate at the cold side. The TEG performance is characterized by a commercial instrument (PEM-2, Riko), with the cold-side temperature is fixed at 293 K and

the hot-side temperature is varied from 473 K to 773 K. The asbestos blanket was further used as heat insulator to reduce the radiant heat.



## **Supporting Figures**

**Figure S1** (a) Room-temperature powder XRD patterns, (b) calculated lattice parameters and interaxial angles α of  $(GeTe)<sub>x</sub>(Ag<sub>0.8</sub>Sb<sub>1.2</sub>Te<sub>2.2</sub>)<sub>100-x</sub>$  (*x* = 75, 76, 77, 78, 79). (c) Temperaturedependent thermal expansion rate (*dL*/*L*0), and (d) calculated coefficient of thermal expansion for *x*  $= 76, 78$  ( $\delta = 0.2$ ) as compared with pristine GeTe.



**Figure S2** Thermoelectric properties of  $(GeTe)<sub>x</sub>(Ag<sub>0.8</sub>Sb<sub>1.2</sub>Te<sub>2.2</sub>)<sub>100-x</sub>$  ( $x = 75, 76, 77, 78, 79$ ). Temperature-dependent (a) electrical conductivity, (b) Seebeck coefficient, (c) power factor, (d) total thermal conductivity, (e) lattice thermal conductivity and (e) *ZT* values.



**Figure S3** Room-temperature powder XRD patterns of  $(GeTe)_{78}(Ag_{1-\delta}Sb_{1+\delta}Te_{2+\delta})_{22}$  ( $\delta = 0.2, 0.21$ , 0.22, 0.23, 0.24).



Figure S4 Thermoelectric properties of *n*-type  $Pb_{0.985}Sb_{0.015}Te$ . Temperature-dependent (a) electrical conductivity, (b) Seebeck coefficient, (c) total thermal conductivity, and (d) *ZT* value.

### **References**

- [1] H. S. Kim, Z. M. Gibbs, Y. Tang, H. Wang and G. J. Snyder, *APL Mater*., 2015, **3**, 041506.
- [2] G. J. Snyder, A. H. Snyder, M. Wood, R. Gurunathan, B. H. Snyder, and C. Niu, *Adv. Mater*., 2020, **32**, 2001537.